NSN 5962-01-363-3446

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
330.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Burn in and electrostatic sensitive and monolithic and programmed and ultraviolet erasable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
25 input
Current Rating Per Characteristic:
60.00 milliamperes forward current, nonrepetitive, peak total value microamperes
Terminal Surface Treatment:
Solder
Product Name:
128k x 8 eprom
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Memory Device Type:
Eprom
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
32 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0